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# Dual Channel, 128-/256-Position, I<sup>2</sup>C, **Nonvolatile Digital Potentiometer**

**Data Sheet** 

AD5122A/AD5142A

#### **FEATURES**

10  $k\Omega$  and 100  $k\Omega$  resistance options Resistor tolerance: 8% maximum

Wiper current: ±6 mA

Low temperature coefficient: 35 ppm/°C

Wide bandwidth: 3 MHz Fast start-up time < 75 us Linear gain setting mode Single- and dual-supply operation Independent logic supply: 1.8 V to 5.5 V Wide operating temperature: -40°C to +125°C

3 mm × 3 mm package option

4 kV ESD protection

### **APPLICATIONS**

Portable electronics level adjustment LCD panel brightness and contrast controls Programmable filters, delays, and time constants **Programmable power supplies** 

### **GENERAL DESCRIPTION**

The AD5122A/AD5142A potentiometers provide a nonvolatile solution for 128-/256-position adjustment applications, offering guaranteed low resistor tolerance errors of ±8% and up to ±6 mA current density in the Ax, Bx, and Wx pins.

The low resistor tolerance and low nominal temperature coefficient simplify open-loop applications as well as applications requiring tolerance matching.

The linear gain setting mode allows independent programming of the resistance between the digital potentiometer terminals, through R<sub>AW</sub> and R<sub>WB</sub> the string resistors, allowing very accurate resistor matching.

The high bandwidth and low total harmonic distortion (THD) ensure optimal performance for ac signals, making it suitable for filter design.

The low wiper resistance of only 40  $\Omega$  at the ends of the resistor array allows for pin-to-pin connection.

The wiper values can be set through an I<sup>2</sup>C-compatible digital interface that is also used to read back the wiper register and EEPROM contents.

The AD5122A/AD5142A are available in a compact, 16-lead,  $3 \text{ mm} \times 3 \text{ mm}$  LFCSP and a 16-lead TSSOP. The parts are guaranteed to operate over the extended industrial temperature range of -40°C to +125°C.

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#### FUNCTIONAL BLOCK DIAGRAM

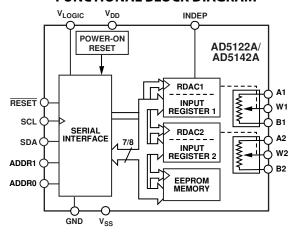


Figure 1.

Table 1. Family Models

Table 1: Talliny Models										
Model	Channel	Position	Interface	Package						
AD5123 <sup>1</sup>	Quad	128	I <sup>2</sup> C	LFCSP						
AD5124	Quad	128	SPI/I <sup>2</sup> C	LFCSP						
AD5124	Quad	128	SPI	TSSOP						
AD5143 <sup>1</sup>	Quad	256	I <sup>2</sup> C	LFCSP						
AD5144	Quad	256	SPI/I <sup>2</sup> C	LFCSP						
AD5144	Quad	256	SPI	TSSOP						
AD5144A	Quad	256	I <sup>2</sup> C	TSSOP						
AD5122	Dual	128	SPI	LFCSP/TSSOP						
AD5122A	Dual	128	I <sup>2</sup> C	LFCSP/TSSOP						
AD5142	Dual	256	SPI	LFCSP/TSSOP						
AD5142A	Dual	256	I <sup>2</sup> C	LFCSP/TSSOP						
AD5121	Single	128	SPI/I <sup>2</sup> C	LFCSP						
AD5141	Single	256	SPI/I <sup>2</sup> C	LFCSP						

<sup>&</sup>lt;sup>1</sup> Two potentiometers and two rheostats.

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# **SPECIFICATIONS**

# **ELECTRICAL CHARACTERISTICS—AD5122A**

 $V_{DD} = 2.3 \text{ V to } 5.5 \text{ V, } V_{SS} = 0 \text{ V; } V_{DD} = 2.25 \text{ V to } 2.75 \text{ V; } V_{SS} = -2.25 \text{ V to } -2.75 \text{ V; } V_{LOGIC} = 1.8 \text{ V to } 5.5 \text{ V, } -40^{\circ}\text{C} < T_{A} < +125^{\circ}\text{C, unless otherwise noted.}$ 

Table 2.

Parameter	Symbol	Test Conditions/Comments	Min	Typ <sup>1</sup>	Max	Unit
DC CHARACTERISTICS—RHEOSTAT MODE (ALL RDACs)						
Resolution	N		7			Bits
Resistor Integral Nonlinearity <sup>2</sup>	R-INL	$R_{AB} = 10 \text{ k}\Omega$				
		$V_{DD} \ge 2.7 \text{ V}$	-1	±0.1	+1	LSB
		$V_{DD} < 2.7 \text{ V}$	-2.5	±1	+2.5	LSB
		$R_{AB} = 100 \text{ k}\Omega$				
		$V_{DD} \ge 2.7 \text{ V}$	-0.5	±0.1	+0.5	LSB
		$V_{DD} < 2.7 \text{ V}$	-1	±0.25	+1	LSB
Resistor Differential Nonlinearity <sup>2</sup>	R-DNL		-0.5	±0.1	+0.5	LSB
Nominal Resistor Tolerance	$\Delta R_{AB}/R_{AB}$		-8	±1	+8	%
Resistance Temperature Coefficient <sup>3</sup>	$(\Delta R_{AB}/R_{AB})/\Delta T \times 10^6$	Code = full scale		35		ppm/°C
Wiper Resistance <sup>3</sup>	R <sub>W</sub>	Code = zero scale				
		$R_{AB} = 10 \text{ k}\Omega$		55	125	Ω
		$R_{AB} = 100 \text{ k}\Omega$		130	400	Ω
Bottom Scale or Top Scale	R <sub>BS</sub> or R <sub>TS</sub>					
		$R_{AB} = 10 \text{ k}\Omega$		40	80	Ω
		$R_{AB} = 100 \text{ k}\Omega$		60	230	Ω
Nominal Resistance Match	R <sub>AB1</sub> /R <sub>AB2</sub>	Code = 0xFF	-1	±0.2	+1	%
DC CHARACTERISTICS—POTENTIOMETER DIVIDER MODE (ALL RDACs)						
Integral Nonlinearity <sup>4</sup>	INL					
		$R_{AB} = 10 \text{ k}\Omega$	-0.5	±0.1	+0.5	LSB
		$R_{AB} = 100 \text{ k}\Omega$	-0.25	±0.1	+0.25	LSB
Differential Nonlinearity <sup>4</sup>	DNL		-0.25	±0.1	+0.25	LSB
Full-Scale Error	V <sub>WFSE</sub>					
		$R_{AB} = 10 \text{ k}\Omega$	-1.5	-0.1		LSB
		$R_{AB} = 100 \text{ k}\Omega$	-0.5	±0.1	+0.5	LSB
Zero-Scale Error	V <sub>wzse</sub>					
		$R_{AB} = 10 \text{ k}\Omega$		1	1.5	LSB
		$R_{AB} = 100 \text{ k}\Omega$		0.25	0.5	LSB
Voltage Divider Temperature Coefficient <sup>3</sup>	$(\Delta V_W/V_W)/\Delta T \times 10^6$	Code = half scale		±5		ppm/°C

Parameter	Symbol	<b>Test Conditions/Comments</b>	Min	Typ <sup>1</sup>	Max	Unit
RESISTOR TERMINALS						
Maximum Continuous Current	I <sub>A</sub> , I <sub>B</sub> , and I <sub>W</sub>					
		$R_{AB} = 10 \text{ k}\Omega$	-6		+6	mA
		$R_{AB} = 100 \text{ k}\Omega$	-1.5		+1.5	mA
Terminal Voltage Range⁵			Vss		$V_{DD}$	V
Capacitance A, Capacitance B <sup>3</sup>	C <sub>A</sub> , C <sub>B</sub>	f = 1 MHz, measured to GND, code = half scale				
		$R_{AB} = 10 \text{ k}\Omega$		25		рF
		$R_{AB} = 100 \text{ k}\Omega$		12		рF
Capacitance W <sup>3</sup>	Cw	f = 1 MHz, measured to GND, code = half scale				
		$R_{AB} = 10 \text{ k}\Omega$		12		рF
		$R_{AB} = 100 \text{ k}\Omega$		5		рF
Common-Mode Leakage Current <sup>3</sup>		$V_A = V_W = V_B$	-500	±15	+500	nA
DIGITAL INPUTS						
Input Logic <sup>3</sup>						
High	V <sub>INH</sub>	$V_{LOGIC} = 1.8 V \text{ to } 2.3 V$	$0.8 \times V_{LOGIC}$			٧
		$V_{LOGIC} = 2.3 \text{ V to } 5.5 \text{ V}$	$0.7 \times V_{LOGIC}$			٧
Low	V <sub>INL</sub>				$0.2 \times V_{LOGIC}$	٧
Input Hysteresis <sup>3</sup>	$V_{HYST}$		$0.1 \times V_{LOGIC}$			V
Input Current <sup>3</sup>	I <sub>IN</sub>				±1	μΑ
Input Capacitance <sup>3</sup>	C <sub>IN</sub>			5		рF
DIGITAL OUTPUTS						
Output High Voltage <sup>3</sup>	Vон	$R_{PULL-UP} = 2.2 \text{ k}\Omega \text{ to } V_{LOGIC}$		$V_{\text{LOGIC}}$		٧
Output Low Voltage <sup>3</sup>	V <sub>OL</sub>	$I_{SINK} = 3 \text{ mA}$			0.4	V
		$I_{SINK} = 6 \text{ mA}, V_{LOGIC} > 2.3 \text{ V}$			0.6	٧
Three-State Leakage Current			-1		+1	μΑ
Three-State Output Capacitance				2		рF
POWER SUPPLIES					_	
Single-Supply Power Range		$V_{SS} = GND$	2.3		5.5	V
Dual-Supply Power Range			±2.25		±2.75	V
Logic Supply Range		Single supply, $V_{SS} = GND$	1.8		$V_{DD}$	V
		Dual supply, V <sub>SS</sub> < GND	2.25		$V_{DD}$	V
Positive Supply Current	I <sub>DD</sub>	$V_{IH} = V_{LOGIC}$ or $V_{IL} = GND$				
		$V_{DD} = 5.5 V$		0.7	5.5	μΑ
		$V_{DD} = 2.3 V$		400		nΑ
Negative Supply Current	I <sub>SS</sub>	$V_{IH} = V_{LOGIC}$ or $V_{IL} = GND$	-5.5	-0.7		μΑ
EEPROM Store Current <sup>3, 6</sup>	I <sub>DD_EEPROM_STORE</sub>	$V_{IH} = V_{LOGIC}$ or $V_{IL} = GND$		2		mA
EEPROM Read Current <sup>3, 7</sup>	I <sub>DD_EEPROM_READ</sub>	$V_{IH} = V_{LOGIC}$ or $V_{IL} = GND$		320		μΑ
Logic Supply Current	I <sub>LOGIC</sub>	$V_{IH} = V_{LOGIC}$ or $V_{IL} = GND$		1	120	nΑ
Power Dissipation <sup>8</sup>	P <sub>DISS</sub>	$V_{IH} = V_{LOGIC}$ or $V_{IL} = GND$		3.5		μW
Power Supply Rejection Ratio	PSRR	$\Delta V_{DD}/\Delta V_{SS} = V_{DD} \pm 10\%$ , code = full scale		-66	-60	dB

Parameter	Symbol	Test Conditions/Comments	Min Typ <sup>1</sup> Max	Unit
DYNAMIC CHARACTERISTICS <sup>9</sup>				
Bandwidth	BW	-3 dB		
		$R_{AB} = 10 \text{ k}\Omega$	3	MHz
		$R_{AB} = 100 \text{ k}\Omega$	0.43	MHz
Total Harmonic Distortion	THD	$V_{DD}/V_{SS} = \pm 2.5 \text{ V}, V_A = 1 \text{ V rms},$ $V_B = 0 \text{ V}, f = 1 \text{ kHz}$		
		$R_{AB} = 10 \text{ k}\Omega$	-80	dB
		$R_{AB} = 100 \text{ k}\Omega$	-90	dB
Resistor Noise Density	en_wB	Code = half scale, $T_A = 25$ °C, $f = 10$ kHz		
		$R_{AB} = 10 \text{ k}\Omega$	7	nV/√Hz
		$R_{AB} = 100 \text{ k}\Omega$	20	nV/√Hz
V <sub>w</sub> Settling Time	ts	$V_A = 5 \text{ V}, V_B = 0 \text{ V}, \text{ from}$ zero scale to full scale, $\pm 0.5 \text{ LSB}$ error band		
		$R_{AB} = 10 \text{ k}\Omega$	2	μs
		$R_{AB} = 100 \text{ k}\Omega$	12	μs
Crosstalk (Cw1/Cw2)	Ст	$R_{AB} = 10 \text{ k}\Omega$	10	nV-sec
		$R_{AB} = 100 \text{ k}\Omega$	25	nV-sec
Analog Crosstalk	C <sub>TA</sub>		-90	dB
Endurance <sup>10</sup>		T <sub>A</sub> = 25°C	1	Mcycles
			100	kcycles
Data Retention <sup>11</sup>			50	Years

<sup>&</sup>lt;sup>1</sup> Typical values represent average readings at 25°C,  $V_{DD} = 5 \text{ V}$ ,  $V_{SS} = 0 \text{ V}$ , and  $V_{LOGIC} = 5 \text{ V}$ .

<sup>&</sup>lt;sup>2</sup> Resistor integral nonlinearity (R-INL) error is the deviation from an ideal value measured between the maximum resistance and the minimum resistance wiper positions. R-DNL measures the relative step change from ideal between successive tap positions. The maximum wiper current is limited to  $(0.7 \times V_{DD})/R_{AB}$ .

<sup>&</sup>lt;sup>3</sup> Guaranteed by design and characterization, not subject to production test.

<sup>&</sup>lt;sup>4</sup> INL and DNL are measured at  $V_{WB}$  with the RDAC configured as a potentiometer divider similar to a voltage output DAC.  $V_A = V_{DD}$  and  $V_B = 0$  V. DNL specification limits of ±1 LSB maximum are guaranteed monotonic operating conditions.

<sup>&</sup>lt;sup>5</sup> Resistor Terminal A, Resistor Terminal B, and Resistor Terminal W have no limitations on polarity with respect to each other. Dual-supply operation enables ground referenced bipolar signal adjustment.

<sup>&</sup>lt;sup>6</sup> Different from operating current; supply current for EEPROM program lasts approximately 30 ms.

<sup>&</sup>lt;sup>7</sup> Different from operating current; supply current for EEPROM read lasts approximately 20 µs.

<sup>&</sup>lt;sup>8</sup>  $P_{DISS}$  is calculated from  $(I_{DD} \times V_{DD}) + (I_{LOGIC} \times V_{LOGIC})$ .

<sup>&</sup>lt;sup>9</sup> All dynamic characteristics use  $V_{DD}/V_{SS} = \pm 2.5 \text{ V}$ , and  $V_{LOGIC} = 2.5 \text{ V}$ .

<sup>&</sup>lt;sup>10</sup> Endurance is qualified to 100,000 cycles per JEDEC Standard 22, Method A117 and measured at -40°C to +125°C.

<sup>11</sup> Retention lifetime equivalent at junction temperature (T<sub>2</sub>) = 125°C per JEDEC Standard 22, Method A117. Retention lifetime, based on an activation energy of 1 eV, derates with junction temperature in the Flash/EE memory.

# **ELECTRICAL CHARACTERISTICS—AD5142A**

 $V_{DD} = 2.3 \text{ V to } 5.5 \text{ V}, V_{SS} = 0 \text{ V}; V_{DD} = 2.25 \text{ V to } 2.75 \text{ V}, V_{SS} = -2.25 \text{ V to } -2.75 \text{ V}; V_{LOGIC} = 1.8 \text{ V to } 5.5 \text{ V}, -40^{\circ}\text{C} < T_A < +125^{\circ}\text{C}, unless otherwise noted.}$ 

Table 3.

Parameter	Symbol Test Conditions/Comments N		Min	Typ <sup>1</sup>	Max	Unit
DC CHARACTERISTICS—RHEOSTAT					<u></u>	
MODE (ALL RDACs)						
Resolution	N		8			Bits
Resistor Integral Nonlinearity <sup>2</sup>	R-INL	$R_{AB} = 10 \text{ k}\Omega$				
		$V_{DD} \ge 2.7 \text{ V}$	-2	±0.2	+2	LSB
		$V_{DD}$ < 2.7 V	-5	±1.5	+5	LSB
		$R_{AB} = 100 \text{ k}\Omega$				
		$V_{DD} \ge 2.7 \text{ V}$	-1	±0.1	+1	LSB
		$V_{DD} < 2.7 \text{ V}$	-2	±0.5	+2	LSB
Resistor Differential Nonlinearity <sup>2</sup>	R-DNL		-0.5	±0.2	+0.5	LSB
Nominal Resistor Tolerance	$\Delta R_{AB}/R_{AB}$		-8	±1	+8	%
Resistance Temperature Coefficient <sup>3</sup>	$(\Delta R_{AB}/R_{AB})/\Delta T \times 10^6$	Code = full scale		35		ppm/°C
Wiper Resistance <sup>3</sup>	Rw	Code = zero scale				
		$R_{AB} = 10 \text{ k}\Omega$		55	125	Ω
		$R_{AB} = 100 \text{ k}\Omega$		130	400	Ω
Bottom Scale or Top Scale	R <sub>BS</sub> or R <sub>TS</sub>					
		$R_{AB} = 10 \text{ k}\Omega$		40	80	Ω
		$R_{AB} = 100 \text{ k}\Omega$		60	230	Ω
Nominal Resistance Match	R <sub>AB1</sub> /R <sub>AB2</sub>	Code = 0xFF	-1	±0.2	+1	%
DC CHARACTERISTICS—POTENTIOMETER DIVIDER MODE (ALL RDACs)						
Integral Nonlinearity <sup>4</sup>	INL					
integral Norminearity	II VE	$R_{AB} = 10 \text{ k}\Omega$	_1	±0.2	+1	LSB
		$R_{AB} = 100 \text{ k}\Omega$	-0.5	±0.1	+0.5	LSB
Differential Nonlinearity <sup>4</sup>	DNL	100 142	-0.5	±0.2	+0.5	LSB
Full-Scale Error	Vwese		0.5	±0.2	10.5	LSB
Tan Scale Error	▼ WF3E	$R_{AB} = 10 \text{ k}\Omega$	-2.5	-0.1		LSB
		$R_{AB} = 100 \text{ k}\Omega$	_1 _1	±0.2	+1	LSB
Zero-Scale Error	V <sub>WZSE</sub>	NAB = 100 KIZ	-'	±0.2	TI	LJD
Zero Scale Litoi	▼ W∠SE	$R_{AB} = 10 \text{ k}\Omega$		1.2	3	LSB
		$R_{AB} = 10 \text{ k}\Omega$		0.5	1	LSB
Voltage Divider Temperature Coefficient <sup>3</sup>	$(\Delta V_W/V_W)/\Delta T \times 10^6$	Code = half scale		±5	1	ppm/°C

Parameter	Symbol	<b>Test Conditions/Comments</b>	Min	Typ <sup>1</sup>	Max	Unit
RESISTOR TERMINALS						
Maximum Continuous Current	I <sub>A</sub> , I <sub>B</sub> , and I <sub>W</sub>					
		$R_{AB} = 10 \text{ k}\Omega$	-6		+6	mA
		$R_{AB} = 100 \text{ k}\Omega$	-1.5		+1.5	mΑ
Terminal Voltage Range⁵			Vss		$V_{DD}$	V
Capacitance A, Capacitance B <sup>3</sup>	C <sub>A</sub> , C <sub>B</sub>	f = 1 MHz, measured to GND, code = half scale				
		$R_{AB} = 10 \text{ k}\Omega$		25		рF
		$R_{AB} = 100 \text{ k}\Omega$		12		pF
Capacitance W <sup>3</sup>	Cw	f = 1 MHz, measured to GND, code = half scale				
		$R_{AB} = 10 \text{ k}\Omega$		12		рF
		$R_{AB} = 100 \text{ k}\Omega$		5		рF
Common-Mode Leakage Current <sup>3</sup>		$V_A = V_W = V_B$	-500	±15	+500	nA
DIGITAL INPUTS						
Input Logic <sup>3</sup>						
High	V <sub>INH</sub>	$V_{LOGIC} = 1.8 \text{ V to } 2.3 \text{ V}$	$0.8 \times V_{LOGIC}$			٧
		$V_{LOGIC} = 2.3 \text{ V to } 5.5 \text{ V}$	$0.7 \times V_{LOGIC}$			V
Low	V <sub>INL</sub>				$0.2 \times V_{LOGIC}$	V
Input Hysteresis <sup>3</sup>	$V_{HYST}$		$0.1 \times V_{LOGIC}$			V
Input Current <sup>3</sup>	I <sub>IN</sub>				±1	μΑ
Input Capacitance <sup>3</sup>	C <sub>IN</sub>			5		рF
DIGITAL OUTPUTS						
Output High Voltage <sup>3</sup>	V <sub>OH</sub>	$R_{PULL-UP} = 2.2 \text{ k}\Omega \text{ to } V_{LOGIC}$		$V_{\text{LOGIC}}$		V
Output Low Voltage <sup>3</sup>	V <sub>OL</sub>	$I_{SINK} = 3 \text{ mA}$			0.4	V
		$I_{SINK} = 6 \text{ mA}, V_{LOGIC} > 2.3 \text{ V}$			0.6	V
Three-State Leakage Current			-1		+1	μΑ
Three-State Output Capacitance				2		рF
POWER SUPPLIES						
Single-Supply Power Range		$V_{SS} = GND$	2.3		5.5	V
Dual-Supply Power Range			±2.25		±2.75	V
Logic Supply Range		Single supply, $V_{SS} = GND$	1.8		$V_{DD}$	V
		Dual supply, V <sub>SS</sub> < GND	2.25		$V_{DD}$	V
Positive Supply Current	I <sub>DD</sub>	$V_{IH} = V_{LOGIC}$ or $V_{IL} = GND$				
		$V_{DD} = 5.5 V$		0.7	5.5	μΑ
		$V_{DD} = 2.3 \text{ V}$		400		nA
Negative Supply Current	I <sub>SS</sub>	$V_{IH} = V_{LOGIC}$ or $V_{IL} = GND$	-5.5	-0.7		μΑ
EEPROM Store Current <sup>3, 6</sup>	I <sub>DD_EEPROM_STORE</sub>	$V_{IH} = V_{LOGIC}$ or $V_{IL} = GND$		2		mA
EEPROM Read Current <sup>3, 7</sup>	I <sub>DD_EEPROM_READ</sub>	$V_{IH} = V_{LOGIC}$ or $V_{IL} = GND$		320		μΑ
Logic Supply Current	I <sub>LOGIC</sub>	$V_{IH} = V_{LOGIC} \text{ or } V_{IL} = GND$		1	120	nΑ
Power Dissipation <sup>8</sup>	P <sub>DISS</sub>	$V_{IH} = V_{LOGIC}$ or $V_{IL} = GND$		3.5		μW
Power Supply Rejection Ratio	PSR	$\Delta V_{DD}/\Delta V_{SS} = V_{DD} \pm 10\%$ , code = full scale		-66	-60	dB

Parameter	Symbol	Test Conditions/Comments	Min Typ <sup>1</sup> Max	Unit
DYNAMIC CHARACTERISTICS9				
Bandwidth	BW	−3 dB		
		$R_{AB} = 10 \text{ k}\Omega$	3	MHz
		$R_{AB} = 100 \text{ k}\Omega$	0.43	MHz
Total Harmonic Distortion	THD	$V_{DD}/V_{SS} = \pm 2.5 \text{ V}, V_A = 1 \text{ V rms}, V_B = 0 \text{ V}, f = 1 \text{ kHz}$		
		$R_{AB} = 10 \text{ k}\Omega$	-80	dB
		$R_{AB} = 100 \text{ k}\Omega$	-90	dB
Resistor Noise Density	e <sub>N_wB</sub>	Code = half scale, $T_A = 25$ °C, $f = 10$ kHz		
		$R_{AB} = 10 \text{ k}\Omega$	7	nV/√Hz
		$R_{AB} = 100 \text{ k}\Omega$	20	nV/√Hz
V <sub>W</sub> Settling Time	ts	$V_A = 5 \text{ V}, V_B = 0 \text{ V}, \text{ from}$ zero scale to full scale, $\pm 0.5 \text{ LSB}$ error band		
		$R_{AB} = 10 \text{ k}\Omega$	2	μs
		$R_{AB} = 100 \text{ k}\Omega$	12	μs
Crosstalk (Cw1/Cw2)	CT	$R_{AB} = 10 \text{ k}\Omega$	10	nV-sec
		$R_{AB} = 100 \text{ k}\Omega$	25	nV-sec
Analog Crosstalk	CTA		-90	dB
Endurance <sup>10</sup>		T <sub>A</sub> = 25°C	1	Mcycles
			100	kcycles
Data Retention <sup>11</sup>			50	Years

<sup>&</sup>lt;sup>1</sup> Typical values represent average readings at 25°C,  $V_{DD} = 5 \text{ V}$ ,  $V_{SS} = 0 \text{ V}$ , and  $V_{LOGIC} = 5 \text{ V}$ .

<sup>&</sup>lt;sup>2</sup> Resistor integral nonlinearity (R-INL) error is the deviation from an ideal value measured between the maximum resistance and the minimum resistance wiper positions. R-DNL measures the relative step change from ideal between successive tap positions. The maximum wiper current is limited to  $(0.7 \times V_{DD})/R_{AB}$ .

<sup>3</sup> Guaranteed by design and characterization, not subject to production test.

<sup>&</sup>lt;sup>4</sup> INL and DNL are measured at  $V_{WB}$  with the RDAC configured as a potentiometer divider similar to a voltage output DAC.  $V_A = V_{DD}$  and  $V_B = 0$  V. DNL specification limits of ±1 LSB maximum are guaranteed monotonic operating conditions.

<sup>&</sup>lt;sup>5</sup> Resistor Terminal A, Resistor Terminal B, and Resistor Terminal W have no limitations on polarity with respect to each other. Dual-supply operation enables ground referenced bipolar signal adjustment.

<sup>&</sup>lt;sup>6</sup> Different from operating current; supply current for EEPROM program lasts approximately 30 ms.

<sup>&</sup>lt;sup>7</sup> Different from operating current; supply current for EEPROM read lasts approximately 20 µs.

<sup>&</sup>lt;sup>8</sup> P<sub>DISS</sub> is calculated from  $(I_{DD} \times V_{DD}) + (I_{LOGIC} \times V_{LOGIC})$ .

<sup>&</sup>lt;sup>9</sup> All dynamic characteristics use  $V_{DD}/V_{SS} = \pm 2.5 \text{ V}$ , and  $V_{LOGIC} = 2.5 \text{ V}$ .

<sup>&</sup>lt;sup>10</sup> Endurance is qualified to 100,000 cycles per JEDEC Standard 22, Method A117 and measured at –40°C to +125°C.

<sup>11</sup> Retention lifetime equivalent at junction temperature (T.) = 125°C per JEDEC Standard 22, Method A117. Retention lifetime, based on an activation energy of 1 eV, derates with junction temperature in the Flash/EE memory.

# INTERFACE TIMING SPECIFICATIONS

 $V_{\rm LOGIC}$  = 1.8 V to 5.5 V; all specifications  $T_{\rm MIN}$  to  $T_{\rm MAX},$  unless otherwise noted.

Table 4.

Parameter <sup>1</sup>	Test Conditions/Comments	Min	Тур	Max	Unit	Description
f <sub>SCL</sub> <sup>2</sup>	Standard mode			100	kHz	Serial clock frequency
	Fast mode			400	kHz	
t <sub>1</sub>	Standard mode	4.0			μs	SCL high time, t <sub>HIGH</sub>
	Fast mode	0.6			μs	
$t_2$	Standard mode	4.7			μs	SCL low time, t <sub>LOW</sub>
	Fast mode	1.3			μs	
t <sub>3</sub>	Standard mode	250			ns	Data setup time, t <sub>SU; DAT</sub>
	Fast mode	100			ns	
t <sub>4</sub>	Standard mode	0		3.45	μs	Data hold time, t <sub>HD; DAT</sub>
	Fast mode	0		0.9	μs	
<b>t</b> <sub>5</sub>	Standard mode	4.7			μs	Setup time for a repeated start condition, t <sub>SU; STA</sub>
	Fast mode	0.6			μs	
<b>t</b> <sub>6</sub>	Standard mode	4			μs	Hold time (repeated) for a start condition, thd; STA
	Fast mode	0.6			μs	
<b>t</b> <sub>7</sub>	Standard mode	4.7			μs	Bus free time between a stop and a start condition, t <sub>BUF</sub>
	Fast mode	1.3			μs	
t <sub>8</sub>	Standard mode	4			μs	Setup time for a stop condition, t <sub>SU; STO</sub>
	Fast mode	0.6			μs	
<b>t</b> 9	Standard mode			1000	ns	Rise time of SDA signal, t <sub>RDA</sub>
	Fast mode	20 + 0.1 C <sub>L</sub>		300	ns	
t <sub>10</sub>	Standard mode			300	ns	Fall time of SDA signal, t <sub>FDA</sub>
	Fast mode	20 + 0.1 C <sub>L</sub>		300	ns	
t <sub>11</sub>	Standard mode			1000	ns	Rise time of SCL signal, t <sub>RCL</sub>
	Fast mode	20 + 0.1 C <sub>L</sub>		300	ns	
t <sub>11A</sub>	Standard mode			1000	ns	Rise time of SCL signal after a repeated start condition and after an acknowledge bit, t <sub>RCL1</sub> (not shown in Figure 3)
	Fast mode	20 + 0.1 C <sub>L</sub>		300	ns	
t <sub>12</sub>	Standard mode			300	ns	Fall time of SCL signal, t <sub>FCL</sub>
	Fast mode	20 + 0.1 C <sub>L</sub>		300	ns	
$t_{SP}^3$	Fast mode	0		50	ns	Pulse width of suppressed spike (not shown in Figure 3)
t <sub>RESET</sub>	0.1			10	μs	RESET low time (not shown in Figure 3)
teeprom_program4			15	50	ms	Memory program time (not shown in Figure 3)
teeprom_readback			7	30	μs	Memory readback time (not shown in Figure 3)
t <sub>POWER_UP</sub> 5				75	μs	Power-on EEPROM restore time (not shown in Figure 3)
treset			30		μs	Reset EEPROM restore time (not shown in Figure 3)

<sup>&</sup>lt;sup>1</sup> Maximum bus capacitance is limited to 400 pF.

<sup>&</sup>lt;sup>2</sup> The SDA and SCL timing is measured with the input filters enabled. Switching off the input filters improves the transfer rate; however, it has a negative effect on the EMC behavior of the part.

<sup>&</sup>lt;sup>3</sup> Input filtering on the SCL and SDA inputs suppresses noise spikes that are less than 50 ns for fast mode.
<sup>4</sup> The EEPROM program time depends on the temperature and EEPROM write cycles. Higher timing is expected at lower temperatures and higher write cycles.

 $<sup>^{5}</sup>$  Maximum time after  $V_{DD} - V_{SS}$  is equal to 2.3 V.

# **SHIFT REGISTER AND TIMING DIAGRAMS**

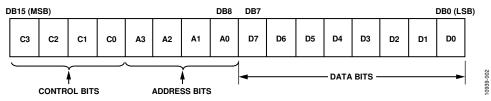


Figure 2. Input Shift Register Contents

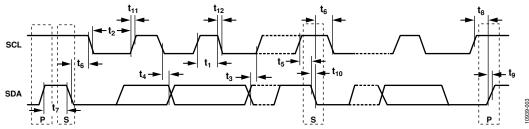


Figure 3. I<sup>2</sup>C Serial Interface Timing Diagram (Typical Write Sequence)

# **ABSOLUTE MAXIMUM RATINGS**

 $T_A = 25$ °C, unless otherwise noted.

#### Table 5.

1 able 5.	
Parameter	Rating
V <sub>DD</sub> to GND	-0.3 V to +7.0 V
V <sub>SS</sub> to GND	+0.3 V to -7.0 V
$V_{DD}$ to $V_{SS}$	7 V
V <sub>LOGIC</sub> to GND	$-0.3 \text{ V to V}_{DD} + 0.3 \text{ V or}$ +7.0 V (whichever is less)
$V_A$ , $V_W$ , $V_B$ to GND	V <sub>SS</sub> – 0.3 V, V <sub>DD</sub> + 0.3 V +7.0 V (whichever is less)
I <sub>A</sub> , I <sub>W</sub> , I <sub>B</sub>	
Pulsed <sup>1</sup>	
Frequency > 10 kHz	
$R_{AW} = 10 \text{ k}\Omega$	±6 mA/d <sup>2</sup>
$R_{AW} = 100 \text{ k}\Omega$	±1.5 mA/d <sup>2</sup>
Frequency ≤ 10 kHz	
$R_{AW} = 10 \text{ k}\Omega$	±6 mA/√d <sup>2</sup>
$R_{AW} = 100 \text{ k}\Omega$	±1.5 mA/√d <sup>2</sup>
Digital Inputs	-0.3 V to V <sub>LOGIC</sub> + 0.3 V or +7 V (whichever is less)
Operating Temperature Range, T <sub>A</sub> <sup>3</sup>	-40°C to +125°C
Maximum Junction Temperature, T <sub>J</sub> Maximum	150°C
Storage Temperature Range	−65°C to +150°C
Reflow Soldering	
Peak Temperature	260°C
Time at Peak Temperature	20 sec to 40 sec
Package Power Dissipation	$(T_J max - T_A)/\theta_{JA}$
ESD⁴	4 kV
FICDM	1.5 kV

<sup>&</sup>lt;sup>1</sup> Maximum terminal current is bounded by the maximum current handling of the switches, maximum power dissipation of the package, and maximum applied voltage across any two of the A, B, and W terminals at a given resistance.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### THERMAL RESISTANCE

 $\theta_{\text{JA}}$  is defined by the JEDEC JESD51 standard, and the value is dependent on the test board and test environment.

**Table 6. Thermal Resistance** 

Package Type	θ <sub>JA</sub>	<b>Ө</b> лс	Unit
16-Lead LFCSP	89.5 <sup>1</sup>	3	°C/W
16-Lead TSSOP	150.4 <sup>1</sup>	27.6	°C/W

<sup>&</sup>lt;sup>1</sup> JEDEC 2S2P test board, still air (0 m/sec airflow).

# **ESD CAUTION**



**ESD** (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

 $<sup>^{2}</sup>$  d = pulse duty factor.

<sup>&</sup>lt;sup>3</sup> Includes programming of EEPROM memory.

<sup>&</sup>lt;sup>4</sup> Human body model (HBM) classification.

# PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

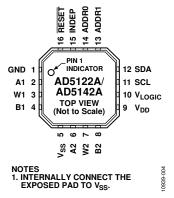


Figure 4. 16-Lead LFCSP Pin Configuration

Table 7. 16-Lead LFCSP Pin Function Descriptions

Pin No.	Mnemonic	Description
1	GND	Ground Pin, Logic Ground Reference.
2	A1	Terminal A of RDAC1. $V_{SS} \le V_A \le V_{DD}$ .
3	W1	Wiper Terminal of RDAC1. $V_{SS} \le V_W \le V_{DD}$ .
4	B1	Terminal B of RDAC1. $V_{SS} \le V_B \le V_{DD}$ .
5	V <sub>SS</sub>	Negative Power Supply. Decouple this pin with 0.1 μF ceramic capacitors and 10 μF capacitors.
6	A2	Terminal A of RDAC2. $V_{SS} \le V_A \le V_{DD}$ .
7	W2	Wiper Terminal of RDAC2. $V_{SS} \le V_W \le V_{DD}$ .
8	B2	Terminal B of RDAC2. $V_{SS} \le V_B \le V_{DD}$ .
9	$V_{DD}$	Positive Power Supply. Decouple this pin with 0.1 μF ceramic capacitors and 10 μF capacitors.
10	V <sub>LOGIC</sub>	Logic Power Supply; 1.8 V to $V_{DD}$ . Decouple this pin with 0.1 $\mu$ F ceramic capacitors and 10 $\mu$ F capacitors.
11	SCL	Serial Clock Line.
12	SDA	Serial Data Input/Output.
13	ADDR1	Programmable Address (ADDR1) for Multiple Package Decoding.
14	ADDR0	Programmable Address (ADDR0) for Multiple Package Decoding.
15	INDEP	Linear Gain Setting Mode at Power-Up. Each string resistor is loaded from its associated memory location. If INDEP is enabled, it cannot be disabled by the software.
16	RESET	Hardware Reset Pin. Refresh the RDAC registers from EEPROM. $\overline{\text{RESET}}$ is activated at logic low. If this pin is not used, tie $\overline{\text{RESET}}$ to $V_{\text{LOGIC}}$ .
	EPAD	Internally Connect the Exposed Pad to V <sub>SS</sub> .

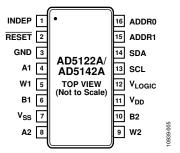


Figure 5. 16-Lead TSSOP Pin Configuration

**Table 8. 16-Lead TSSOP Pin Function Descriptions** 

Pin No.	Mnemonic	Description
1	INDEP	Linear Gain Setting Mode at Power-Up. Each string resistor is loaded from its associated memory location. If INDEP is enabled, it cannot be disabled by the software.
2	RESET	Hardware Reset Pin. Refresh the RDAC registers from EEPROM. $\overline{\text{RESET}}$ is activated at logic low. If this pin is not used, tie $\overline{\text{RESET}}$ to $V_{\text{LOGIC}}$ .
3	GND	Ground Pin, Logic Ground Reference.
4	A1	Terminal A of RDAC1. $V_{SS} \le V_A \le V_{DD}$ .
5	W1	Wiper Terminal of RDAC1. $V_{SS} \le V_W \le V_{DD}$ .
6	B1	Terminal B of RDAC1. $V_{SS} \le V_B \le V_{DD}$ .
7	$V_{SS}$	Negative Power Supply. Decouple this pin with 0.1 μF ceramic capacitors and 10 μF capacitors.
8	A2	Terminal A of RDAC2. $V_{SS} \le V_A \le V_{DD}$ .
9	W2	Wiper Terminal of RDAC2. $V_{SS} \le V_W \le V_{DD}$ .
10	B2	Terminal B of RDAC2. $V_{SS} \le V_B \le V_{DD}$ .
11	$V_{\text{DD}}$	Positive Power Supply. Decouple this pin with 0.1 μF ceramic capacitors and 10 μF capacitors.
12	$V_{LOGIC}$	Logic Power Supply; 1.8 V to V <sub>DD</sub> . Decouple this pin with 0.1 μF ceramic capacitors and 10 μF capacitors.
13	SCL	Serial Clock Line.
14	SDA	Serial Data Input/Output.
15	ADDR1	Programmable Address (ADDR1) for Multiple Package Decoding.
16	ADDR0	Programmable Address (ADDR0) for Multiple Package Decoding.

# TYPICAL PERFORMANCE CHARACTERISTICS

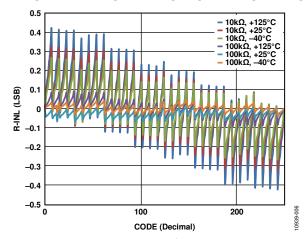


Figure 6. R-INL vs. Code (AD5142A)

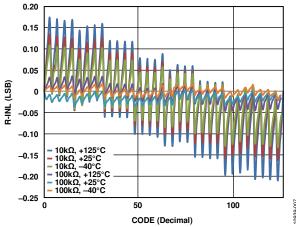


Figure 7. R-INL vs. Code (AD5122A)

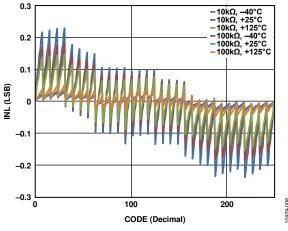


Figure 8. INL vs. Code (AD5142A)

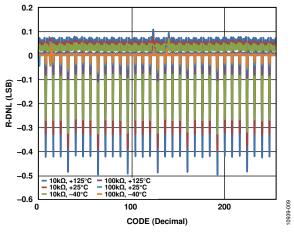


Figure 9. R-DNL vs. Code (AD5142A)

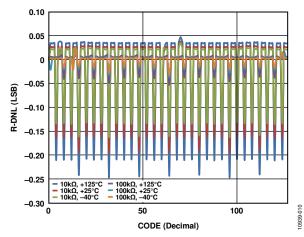


Figure 10. R-DNL vs. Code (AD5122A)

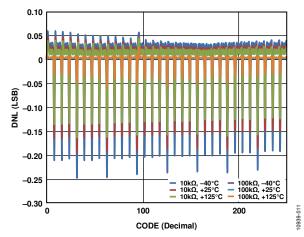


Figure 11. DNL vs. Code (AD5142A)

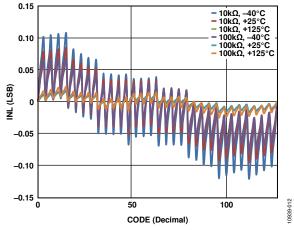


Figure 12. INL vs. Code (AD5122A)

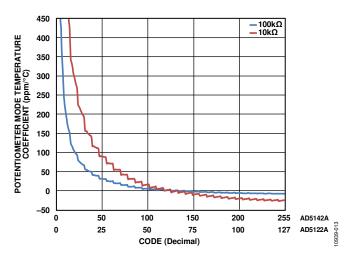


Figure 13. Potentiometer Mode Temperature Coefficient ( $(\Delta V_W/V_W)/\Delta T \times 10^6$ ) vs. Code

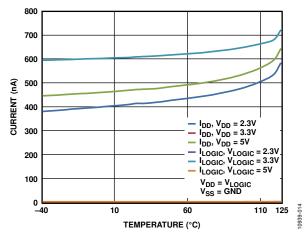


Figure 14. Supply Current vs. Temperature

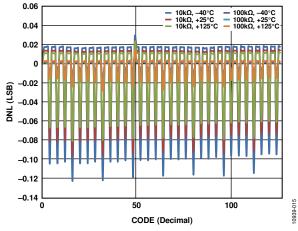


Figure 15. DNL vs. Code (AD5122A)

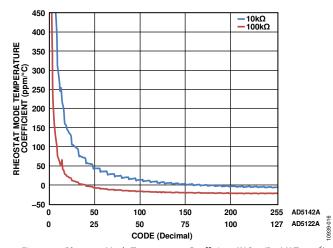


Figure 16. Rheostat Mode Temperature Coefficient (( $\Delta R_{WB}/R_{WB}$ )/ $\Delta T \times 10^6$ ) vs. Code

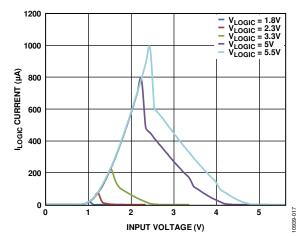


Figure 17. ILOGIC Current vs. Digital Input Voltage

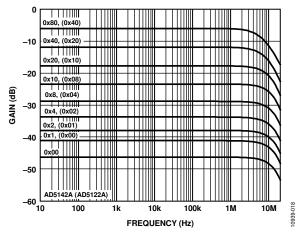


Figure 18. 10  $k\Omega$  Gain vs. Frequency and Code

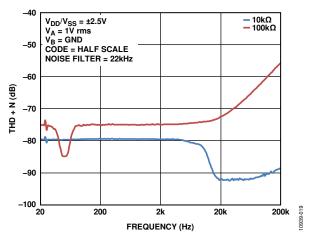


Figure 19. Total Harmonic Distortion Plus Noise (THD + N) vs. Frequency

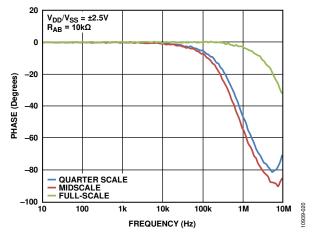


Figure 20. Normalized Phase Flatness vs. Frequency,  $R_{AB}=10~k\Omega$ 

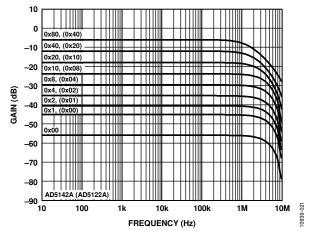


Figure 21. 100 k $\Omega$  Gain vs. Frequency and Code

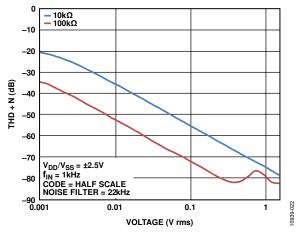


Figure 22. Total Harmonic Distortion Plus Noise (THD + N) vs. Amplitude

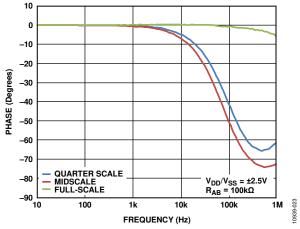


Figure 23. Normalized Phase Flatness vs. Frequency,  $R_{AB} = 100 \text{ k}\Omega$ 

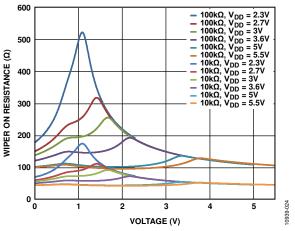


Figure 24. Incremental Wiper On Resistance vs.  $V_{DD}$ 

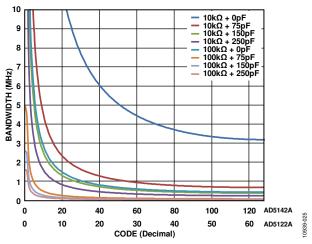


Figure 25. Maximum Bandwidth vs. Code and Net Capacitance

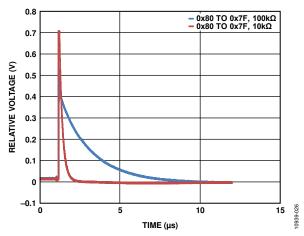


Figure 26. Maximum Transition Glitch

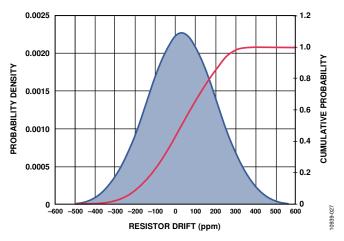


Figure 27. Resistor Lifetime Drift

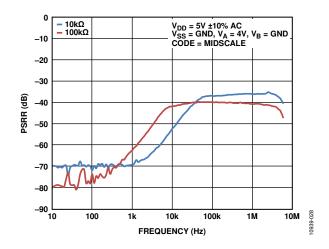


Figure 28. Power Supply Rejection Ratio (PSRR) vs. Frequency

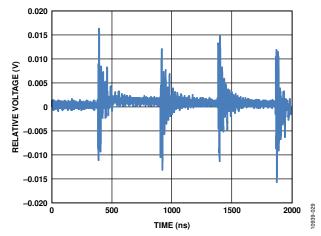


Figure 29. Digital Feedthrough

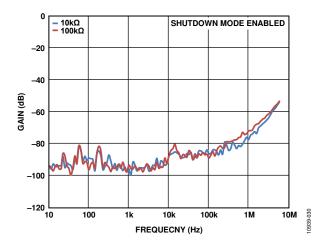


Figure 30. Shutdown Isolation vs. Frequency

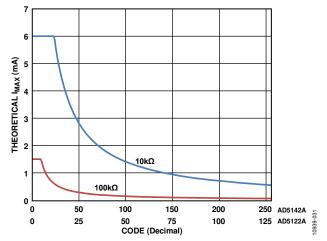


Figure 31. Theoretical Maximum Current vs. Code

# **TEST CIRCUITS**

Figure 32 to Figure 36 define the test conditions used in the Specifications section.

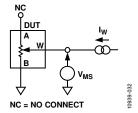


Figure 32. Resistor Integral Nonlinearity Error (Rheostat Operation; R-INL, R-DNL)

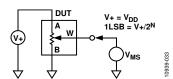


Figure 33. Potentiometer Divider Nonlinearity Error (INL, DNL)

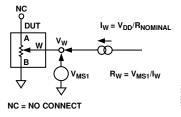


Figure 34. Wiper Resistance

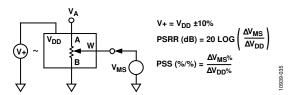


Figure 35. Power Supply Sensitivity and Power Supply Rejection Ratio (PSS, PSRR)

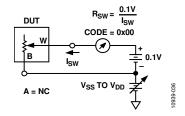


Figure 36. Incremental On Resistance

# THEORY OF OPERATION

The AD5122A/AD5142A digital programmable potentiometers are designed to operate as true variable resistors for analog signals within the terminal voltage range of  $V_{\text{SS}} < V_{\text{TERM}} < V_{\text{DD}}$ . The resistor wiper position is determined by the RDAC register contents. The RDAC register acts as a scratchpad register that allows unlimited changes of resistance settings. A secondary register (the input shift register) can be used to preload the RDAC register data.

The RDAC register can be programmed with any position setting using the I<sup>2</sup>C interface. When a desirable wiper position is found, this value can be stored in the EEPROM memory. Thereafter, the wiper position is always restored to that position for subsequent power-ups. The storing of EEPROM data takes approximately 15 ms; during this time, the device is locked and does not acknowledge any new command, preventing any changes from taking place.

### **RDAC REGISTER AND EEPROM**

The RDAC register directly controls the position of the digital potentiometer wiper. For example, when the RDAC register is loaded with 0x80 (AD5142A, 256 taps), the wiper is connected to half scale of the variable resistor. The RDAC register is a standard logic register; there is no restriction on the number of changes allowed.

It is possible to both write to and read from the RDAC register using the digital interface (see Table 10).

The contents of the RDAC register can be stored to the EEPROM using Command 9 (see Table 10). Thereafter, the RDAC register always sets at that position for any future on-off-on power supply sequence. It is possible to read back data saved into the EEPROM with Command 3 (see Table 10).

Alternatively, the EEPROM can be written to independently using Command 11 (see Table 16).

## **INPUT SHIFT REGISTER**

For the AD5122A/AD5142A, the input shift register is 16 bits wide, as shown in Figure 2. The 16-bit word consists of four control bits, followed by four address bits and by eight data bits.

If the AD5122A RDAC or EEPROM registers are read from or written to, the lowest data bit (Bit 0) is ignored.

Data is loaded MSB first (Bit 15). The four control bits determine the function of the software command, as listed in Table 10 and Table 16.

### I<sup>2</sup>C SERIAL DATA INTERFACE

The AD5122A/AD5142A have 2-wire, I<sup>2</sup>C-compatible serial interfaces. The device can be connected to an I<sup>2</sup>C bus as a slave device, under the control of a master device. See Figure 3 for a timing diagram of a typical write sequence.

The AD5122A/AD5142A supports standard (100 kHz) and fast (400 kHz) data transfer modes. Support is not provided for 10-bit addressing and general call addressing.

The 2-wire serial bus protocol operates as follows:

- The master initiates a data transfer by establishing a start condition, which is when a high-to-low transition on the SDA line occurs while SCL is high. The following byte is the address byte, which consists of the 7-bit slave address and an R/W bit. The slave device corresponding to the transmitted address responds by pulling SDA low during the ninth clock pulse (this is called the acknowledge bit). At this stage, all other devices on the bus remain idle while the selected device waits for data to be written to, or read from, its shift register.
  - If the  $R/\overline{W}$  bit is set high, the master reads from the slave device. However, if the  $R/\overline{W}$  bit is set low, the master writes to the slave device.
- Data is transmitted over the serial bus in sequences of nine clock pulses (eight data bits followed by an acknowledge bit).
   The transitions on the SDA line must occur during the low period of SCL and remain stable during the high period of SCL.
- 3. When all data bits have been read from or written to, a stop condition is established. In write mode, the master pulls the SDA line high during the tenth clock pulse to establish a stop condition. In read mode, the master issues a no acknowledge for the ninth clock pulse (that is, the SDA line remains high). The master then brings the SDA line low before the tenth clock pulse, and then high again during the tenth clock pulse to establish a stop condition.

## I<sup>2</sup>C ADDRESS

The facility to make hardwired changes to ADDR allows the user to incorporate up to nine of these devices on one bus as outlined in Table 9.

**Table 9. Device Address Selection** 

ADDR0 Pin	ADDR1 Pin	7-Bit I <sup>2</sup> C Device Address
V <sub>LOGIC</sub>	V <sub>LOGIC</sub>	0100000
No connect1	V <sub>LOGIC</sub>	0100010
GND	V <sub>LOGIC</sub>	0100011
$V_{LOGIC}$	No connect <sup>1</sup>	0101000
No connect1	No connect <sup>1</sup>	0101010
GND	No connect <sup>1</sup>	0101011
$V_{LOGIC}$	GND	0101100
No connect1	GND	0101110
GND	GND	0101111

 $<sup>^{1}</sup>$  Not available in bipolar mode (V<sub>SS</sub> < 0 V) or in low voltage mode (V<sub>LOGIC</sub> = 1.8 V).

**Table 10. Reduced Commands Operation Truth Table** 

Command	Bit		ntrol I 5:DB	12]	Bit		ress 11:DB	8]¹			Data	Bits[	DB7:[	)B0]¹							
Number	C3	C2	<b>C</b> 1	C0	А3	A2	<b>A</b> 1	A0	D7	D6	D5	D4	D3	D2	D1	D0	Operation	Operation			
0	0	0	0	0	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	NOP: do	nothing			
1	0	0	0	1	0	0	0	A0	D7	D6	D5	D4	D3	D2	D1	D0	Write contents of serial register data to RDAC				
2	0	0	1	0	0	0	0	A0	D7	D6	D5	D4	D3	D2	D1	D0	Write contents of serial register data to input shift register				
3	0	0	1	1	0	0	A1	Α0	Χ	Χ	Χ	Χ	Χ	Χ	D1	D0	Read back contents				
																	D1 D0 Data				
																	0	1	EEPROM		
																	1	1	RDAC		
9	0	1	1	1	0	0	0	A0	Χ	Χ	Χ	Χ	Χ	Χ	Χ	1	Copy RD	AC registe	r to EEPROM		
10	0	1	1	1	0	0	0	Α0	Χ	Χ	Χ	Χ	Χ	Χ	Χ	0	Copy EEI	PROM into	RDAC		
14	1	0	1	1	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Software	reset			
15	1	1	0	0	А3	0	0	Α0	Х	Χ	Χ	Χ	Χ	Χ	Χ	D0	Software shutdown				
																	D0 Condition				
																	0 Normal mode				
																	1	Shutdov	vn mode		

 $<sup>^{1}</sup>$  X = don't care.

Table 11. Reduced Address Bits Table

A3	A2	A1	A0	Channel	Stored Channel Memory
1	X <sup>1</sup>	X <sup>1</sup>	X <sup>1</sup>	All channels	Not applicable
0	0	0	0	RDAC1	RDAC1
0	0	0	1	RDAC2	Not applicable
0	0	1	0	Not applicable	RDAC2

<sup>&</sup>lt;sup>1</sup> X = don't care.

#### **ADVANCED CONTROL MODES**

The AD5122A/AD5142A digital potentiometers include a set of user programming features to address the wide number of applications for these universal adjustment devices (see Table 16 and Table 18).

Key programming features include the following:

- Input register
- Linear gain setting mode
- A low wiper resistance feature
- Linear increment and decrement instructions
- ±6 dB increment and decrement instructions
- Burst mode
- Reset
- Shutdown mode

## **Input Register**

The AD5122A/AD5142A include one input register per RDAC register. These registers allow preloading of the value for the associated RDAC register. These registers can be written to using Command 2 and read back from using Command 3 (see Table 16).

This feature allows a synchronous update of one or both RDAC registers at the same time.

The transfer from the input register to the RDAC register is done synchronously by Command 8 (see Table 16).

If new data is loaded in an RDAC register, this RDAC register automatically overwrites the associated input register.

## Linear Gain Setting Mode

The patented architecture of the AD5122A/AD5142A allows the independent control of each string resistor,  $R_{AW}$ , and  $R_{WB}$ . To enable linear gain setting mode, use Command 16 (see Table 16) to set Bit D2 of the control register (see Table 18).

This mode of operation can control the potentiometer as two independent rheostats connected at a single point, W terminal, as opposed to potentiometer mode where each resistor is complementary,  $R_{\rm AW} = R_{\rm AB} - R_{\rm WB}$ .

This mode enables a second input and an RDAC register per channel, as shown in Table 16; however, the actual RDAC contents remain unchanged. The same operations are valid for potentiometer and linear gain setting mode.

If the INDEP pin is pulled high, the device powers up in linear gain setting mode and loads the values stored in the associated memory locations for each channel (see Table 17). The INDEP pin and the D2 bit are connected internally to a logic OR gate; if one or both are set to 1, the parts cannot operate in potentiometer mode.

### Low Wiper Resistance Feature

The AD5122A/AD5142A include two commands to reduce the wiper resistance between the terminals when the device achieves full scale or zero scale. These extra positions are called bottom scale, BS, and top scale, TS. The resistance between Terminal A and Terminal W at top scale is specified as  $R_{\rm TS}$ . Similarly, the bottom scale resistance between Terminal B and Terminal W is specified as  $R_{\rm BS}$ .

The contents of the RDAC registers are unchanged by entering in these positions. There are three ways to exit from top scale and bottom scale: by using Command 12 or Command 13 (see Table 16); by loading new data in an RDAC register, which includes increment/decrement operations; or by entering shutdown mode, Command 15 (see Table 16).

Table 12 and Table 13 show the truth tables for the top scale position and the bottom scale position, respectively, when potentiometer or linear gain setting mode is enabled.

**Table 12. Top Scale Truth Table** 

Linear Gain	Setting Mode	Potentiometer Mode				
R <sub>AW</sub>	R <sub>WB</sub>	R <sub>AW</sub>	R <sub>WB</sub>			
R <sub>AB</sub>	R <sub>AB</sub>	R <sub>TS</sub>	R <sub>AB</sub>			

**Table 13. Bottom Scale Truth Table** 

Linear Gain S	Setting Mode	Potentiometer Mode				
R <sub>AW</sub>	R <sub>WB</sub>	R <sub>AW</sub>	R <sub>WB</sub>			
R <sub>TS</sub>	R <sub>BS</sub>	R <sub>AB</sub>	R <sub>BS</sub>			

### **Linear Increment and Decrement Instructions**

The increment and decrement commands (Command 4 and Command 5 in Table 16) are useful for linear step adjustment applications. These commands simplify microcontroller software coding by allowing the controller to send an increment or decrement command to the device. The adjustment can be individual or in a ganged potentiometer arrangement, where all wiper positions are changed at the same time.

For an increment command, executing Command 4 automatically moves the wiper to the next RDAC position. This command can be executed in a single channel or in multiple channels.

#### ±6 dB Increment and Decrement Instructions

Two programming instructions produce logarithmic taper increment or decrement of the wiper position control by an individual potentiometer or by a ganged potentiometer arrangement where all RDAC register positions are changed simultaneously. The +6 dB increment is activated by Command 6, and the -6 dB decrement is activated by Command 7 (see Table 16). For example, starting with the zero-scale position and executing Command 6 ten times moves the wiper in 6 dB steps to the full-scale position. When the wiper position is near the maximum setting, the last 6 dB increment instruction causes the wiper to go to the full-scale position (see Table 14).

Incrementing the wiper position by +6 dB essentially doubles the RDAC register value, whereas decrementing the wiper position by -6 dB halves the register value. Internally, the AD5122A/AD5142A use shift registers to shift the bits left and right to achieve a  $\pm 6$  dB increment or decrement. These functions are useful for various audio/video level adjustments, especially for white LED brightness settings in which human visual responses are more sensitive to large adjustments than to small adjustments.

Table 14. Detailed Left Shift and Right Shift Functions for the  $\pm 6$  dB Step Increment and Decrement

Left Shift (+6 dB/Step)	Right Shift (–6 dB/Step)
0000 0000	1111 1111
0000 0001	0111 1111
0000 0010	0011 1111
0000 0100	0001 1111
0000 1000	0000 1111
0001 0000	0000 0111
0010 0000	0000 0011
0100 0000	0000 0001
1000 0000	0000 0000
1111 1111	0000 0000

#### **Burst Mode**

By enabling the burst mode, multiple data bytes can be sent to the part consecutively. After the command byte, the part interprets the following consecutive bytes as data bytes for the command.

A new command can be sent by generating a repeat start or by a stop and start condition.

The burst mode is activated by setting Bit D3 of the control register (see Table 18).

#### Reset

The AD5122A/AD5142A can be reset through software by executing Command 14 (see Table 16) or through hardware on the low pulse of the  $\overline{RESET}$  pin. The reset command loads the RDAC registers with the contents of the EEPROM and takes approximately 30  $\mu$ s. The EEPROM is preloaded to midscale at the factory, and initial power-up is, accordingly, at midscale. Tie  $\overline{RESET}$  to  $V_{LOGIC}$  if the  $\overline{RESET}$  pin is not used.

### Shutdown Mode

The AD5122A/AD5142A can be placed in shutdown mode by executing the software shutdown command, Command 15 (see Table 16), and setting the LSB (D0) to 1. This feature places the RDAC in a zero power consumption state where the device operates in potentiometer mode, Terminal A is open-circuited and the wiper, Terminal W, is connected to Terminal B; however, a finite wiper resistance of 40  $\Omega$  is present. When the device is configured in linear gain setting mode, the resistor addressed, Raw or Rwb, is internally placed at high impedance. Table 15 shows the truth table depending on the device operating mode. The contents of the RDAC register are unchanged by entering shutdown mode. However, all commands listed in Table 16 are supported while in shutdown mode. Execute Command 15 (see Table 16) and set the LSB (D0) to 0 to exit shutdown mode.

Table 15. Truth Table for Shutdown Mode

Linear Gain S	Potentiometer Mode			
R <sub>AW</sub>	R <sub>WB</sub>	R <sub>AW</sub>	RwB	
High impedance	High impedance	High impedance	R <sub>BS</sub>	

### **EEPROM OR RDAC REGISTER PROTECTION**

The EEPROM and RDAC registers can be protected by disabling any update to these registers. This can be done by using software or by using hardware. If these registers are protected by software, set Bit D0 and/or Bit D1 (see Table 18), which protects the RDAC and EEPROM registers independently.

When RDAC is protected, the only operation allowed is to copy the EEPROM into the RDAC register.

#### **INDEP PIN**

If the INDEP pin is pulled high at power-up, the part operates in linear gain setting mode, loading each string resistor,  $R_{\text{AWX}}$  and  $R_{\text{WBX}}$ , with the value stored into the EEPROM (see Table 17). If the pin is pulled low, the part powers up in potentiometer mode.

The INDEP pin and the D2 bit are connected internally to a logic OR gate; if one or both are set to 1, the part cannot operate in potentiometer mode (see Table 18).

**Table 16. Advanced Command Operation Truth Table** 

Command	В	Com Bits[DB	mand 15:DB	12]	Bit		lress 11:DB	<b>8</b> ]¹	Data Bits[DB7:DB0] <sup>1</sup>										
Number	С3	C2	<b>C</b> 1	C0	А3	<b>A2</b>	<b>A</b> 1	A0	D7	D6	D5	D4	D3	D2	D1	D0	Oper	ation	
0	0	0	0	0	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	NOP:	do notl	ning
1	0	0	0	1	0	A2	0	A0	D7	D6	D5	D4	D3	D2	D1	D0			ts of serial to RDAC
2	0	0	1	0	0	A2	0	A0	D7	D6	D5	D4	D3	D2	D1	D0	regist regist	er data er	ts of serial to input
3	0	0	1	1	Х	A2	A1	A0	Χ	Χ	Χ	Χ	Χ	Χ	D1	D0	Read	back co	ntents
																	D1	D0	Data
																	0	0	Input register
																	0	1	EEPROM
																	1	0	Control
																			register
																	1	1	RDAC
4	0	1	0	0	А3	A2	0	A0	Χ	Χ	Χ	Χ	Χ	Χ	Χ	1	Linear RDAC increment		
5	0	1	0	0	А3	A2	0	A0	Χ	Χ	Χ	Χ	Χ	Χ	Χ	0	Linear RDAC decrement		
6	0	1	0	1	А3	A2	0	A0	Χ	Χ	Χ	Χ	Χ	Χ	Χ	1	+6 dB RDAC increment		
7	0	1	0	1	А3	A2	0	Α0	Χ	Χ	Χ	Χ	Χ	Χ	Χ	0	−6 dB RDAC decrement		
8	0	1	1	0	0	A2	0	A0	Х	Х	Х	Х	Х	Х	Х	Х	Copy input register to RDAC (software LRDAC)		
9	0	1	1	1	0	A2	0	Α0	Х	Х	Х	Х	Х	Х	Χ	1	Copy		egister to
10	0	1	1	1	0	A2	0	Α0	Х	Х	Χ	Χ	Χ	Χ	Χ	0	Сору	EEPRO	M into RDAC
11	1	0	0	0	0	0	A1	A0	D7	D6	D5	D4	D3	D2	D1	D0			ts of serial
																			to EEPROM
12	1	0	0	1	А3	A2	0	Α0	1	Χ	Χ	Χ	Χ	Χ	Χ	D0	Top s	cale	
																	D0 =	0; norm	al mode
																	D0 =	1; shut	down mode
13	1	0	0	1	А3	A2	0	Α0	0	Χ	Χ	Χ	Χ	Χ	Χ	D0	Botto	m scale	1
																	D0 =	1; entei	•
																	D0 = 0; exit		
14	1	0	1	1	Х	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Χ	Software reset		
15	1	1	0	0	А3	A2	0	Α0	Χ	Χ	Χ	Х	Х	Х	Χ	D0	Software shutdown		
																	D0 =	0; norm	al mode
																			e placed in
16	1	1	0	1	Х	Χ	Χ	Χ	Х	Χ	Χ	Χ	D3	D2	D1	D0	Shutdown mode  Copy serial register data to control register		

 $<sup>^{1}</sup>$  X = don't care.

Table 17. Address Bits

				Potention	neter Mode	Linear Gain S	Setting Mode	Stored Channel
А3	A2	<b>A</b> 1	A0	Input Register	RDAC Register	Input Register	RDAC Register	Memory
1	X <sup>1</sup>	X <sup>1</sup>	X <sup>1</sup>	All channels	All channels	All channels	All channels	Not applicable
0	0	0	0	RDAC1	RDAC1	R <sub>WB1</sub>	R <sub>WB1</sub>	RDAC1/R <sub>WB1</sub>
0	1	0	0	Not applicable	Not applicable	R <sub>AW1</sub>	R <sub>AW1</sub>	Not applicable
0	0	0	1	RDAC2	RDAC2	R <sub>WB2</sub>	R <sub>WB2</sub>	R <sub>AW1</sub>
0	1	0	1	Not applicable	Not applicable	R <sub>AW2</sub>	R <sub>AW2</sub>	Not applicable
0	0	1	0	Not applicable	Not applicable	Not applicable	Not applicable	RDAC2/R <sub>WB2</sub>
0	0	1	1	Not applicable	Not applicable	Not applicable	Not applicable	R <sub>AW2</sub>

 $<sup>^{1}</sup>$  X = don't care.

# **Table 18. Control Register Bit Descriptions**

Bit Name	Description
D0	RDAC register write protect
	0 = wiper position frozen to value in EEPROM memory
	1 = allows update of wiper position through digital interface (default)
D1	EEPROM program enable
	0 = EEPROM program disabled
	1 = enables device for EEPROM program (default)
D2	Linear setting mode/potentiometer mode
	0 = potentiometer mode (default)
	1 = linear gain setting mode
D3	Burst mode (I <sup>2</sup> C only)
	0 = disabled (default)
	1 = enabled (no disable after stop or repeated start condition)